

Thermal neutron induces Single-Event Upsets in the FPGA used in particle physics experiments

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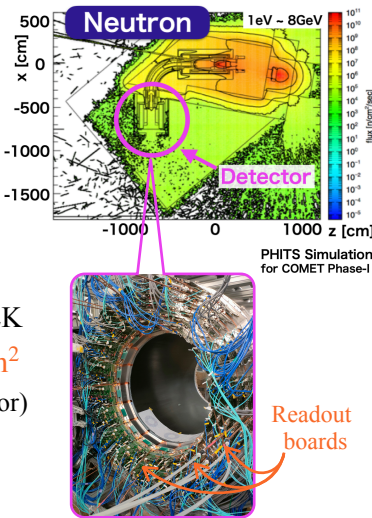
Introduction

Radiation on Particle Physics Experiments

To explore beyond the Standard Model, beams generated by accelerators are becoming **higher intensity, higher luminosity and higher energy.**
→ **increase background radiations** (neutron, gamma, proton, etc.)
→ **affects electronics.**

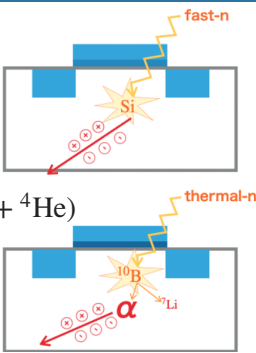
e.g.) COMET^[1] @ J-PARC, SuperKEKB/Belle II^[2] @ KEK
Estimated cumulative neutron dose $\sim 10^{12} \text{ n}_{1\text{-MeVeq}}/\text{cm}^2$ (Including safety factor)

There is a large amount of **thermal neutrons** around the detector readout electronics.



Neutron effect

- Fast neutron ($> 0.1 \text{ MeV}$): nuclear reaction with Si
→ **emit Ion particle**
 - Thermal neutron ($< 1 \text{ eV}$): capture reaction with ^{10}B
→ **emit α particle** ($^{10}\text{B} + n \rightarrow ^7\text{Li} + ^4\text{He}$)
- Induce electron-hole pairs
→ **Change the logic state (Single-Event Upset, SEU)**
Counterplan : neutron shield, error-correcting code, etc.



Semiconductor design & SEU occurred by thermal neutron

Trend : ^{10}B less oxide film is used $\cdot \cdot \cdot$ SEUs by thermal neutron decreased...?
→ Some studies reported SEUs induced by thermal neutrons [3], [4].
It might still contain ^{10}B ? / SEU trends vary depending on the product type.

Motivation of this study

To **estimate SEUs caused by thermal neutrons** in an **FPGA**
(For fast neutrons, it has been studied in [5].)

Measurement

We measured **SEU counts on FPGA** and **fluences of thermal and fast neutrons** by irradiating neutron (n) beams in several different setups.

FPGA Artix-7 on the COMET readout board ROESTI [6] $12.1\text{mm} \times 11.1\text{mm}$
28-nm CMOS process FPGA (AMD Inc.)

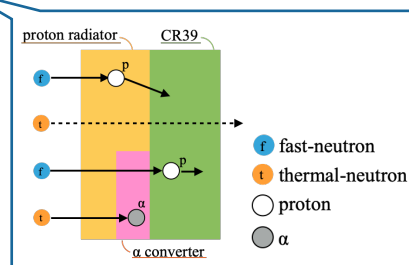
Facility Tandem accelerator at Kobe Univ.

- Beam : 3 MeV deuteron (d)
- Reaction : $^9\text{Be} + d(3 \text{ MeV}) \rightarrow ^{10}\text{B} + n$
- Neutron energy : 2 MeV ($< 7 \text{ MeV}$)
- Neutron flux : $4.8 \times 10^6 \text{ Hz/cm}^2/\mu\text{A}$ at 10 cm from a target

Neutron measurement (CR39)

- CR39 (Nagase Landauer Ltd.)
- Solid-state track detector
- Plastic consisting of $\text{C}_{12}\text{H}_{18}\text{O}_7$
- Contain proton radiator, and α converter
- Measure **fast** or **thermal** neutrons, respectively

specification [7]	thermal	fast
Dose range	0.1 mSv \sim 6 mSv	0.1 mSv \sim 50 mSv
Energy range	0.025 eV \sim 0.5 eV	24 keV \sim 15 MeV



- + Record the **deuteron beam current** in a data logger (GRAPHTEC GL840)
(To normalize SEU rate by beam charge) charge \propto irradiated neutrons

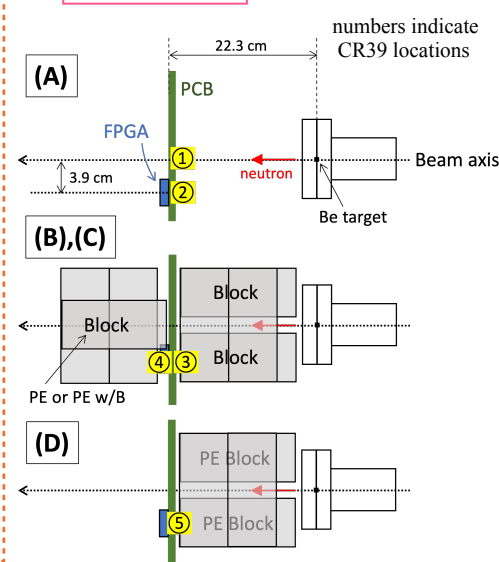
Setup & SEU Measurement

- Put some blocks around the beam
- Irradiated **FPGA** and **CR39**
- Detected and corrected SEUs by **Soft Error Mitigation (SEM) IP core** [8]
- Recorded deuteron beam current



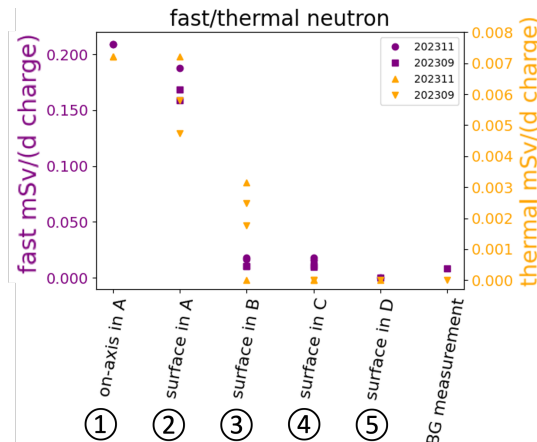
data logger on 2F

- (A) : **Without blocks (reference)**
CR39 - ① On-axis, ② FPGA surface
- (B) : **With Polyethylene (PE) blocks (degrade or reflect fast neutrons)**
CR39 - ③ FPGA surface
- (C) : **With PE blocks containing B_2O_3 (shield both fast and thermal neutrons)**
CR39 - ④ FPGA surface
- (D) : **Remove blocks behind FPGA from (B) (investigate the impact of behind block = reflected-derived thermal neutrons)**
CR39 - ⑤ FPGA surface
- Background (BG) CR39 - no irradiation



Result & Discussion

Neutron measurement



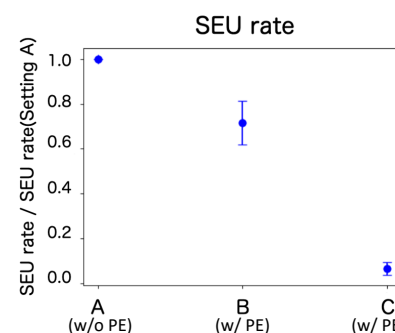
- Without blocks, both fast and thermal neutrons were irradiated. (①, ②)
- The one-minute measurement in 202309-thermal (\blacktriangle) was too short to detect in ③.
- Thermal and fast neutrons are successfully shielded in ④ due to **B_2O_3 -containing blocks**.
- Most thermal neutrons **came from the reflection of the behind block in ⑤** compare to ③.

→ Confirmed neutron energy trend
A : fast,thermal
B : thermal
C : neither fast nor thermal

SEU measurement

Setup	SEU count	deuteron charge[C]	SEU / (d charge)
A	113	4.9×10^3	2.3×10^{-2}
B	104	6.2×10^3	1.7×10^{-2}
C	6	4.0×10^3	1.5×10^{-3}

SEU counts increased in proportion to the beam charge →



← The SEU rate on each setups relative to the result of A

- ★ **It was found that SEUs occurred due to thermal neutrons.**
- ★ **Shielding of B_2O_3 -containing blocks greatly contributes to reducing the SEUs.**

Conclusion & Future

- Particle physics experiments using **the beam of high-intensity, luminosity, and energy** require consideration of radiation effects on electronics.
- Fast neutrons** and **thermal neutrons** can induce charged particles inside transistors through different processes, which can **cause SEUs**.
- We investigated SEUs induced by thermal neutrons using an **FPGA employed in a particle experiment**.
- By placing polyethylene blocks, we succeeded in producing thermal neutrons from a tandem accelerator and **observed SEUs caused by thermal neutrons**.
- We showed that **it is necessary to consider the influence of thermal neutrons in the experiments and the usefulness of countermeasures such as shielding**.

Future work

- To better understand the rate of SEU
★ Simulating a detailed neutron energy distribution ★ Measuring the energy
- Investigate where and how much ^{10}B is contained by elemental analysis

Acknowledgement

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